

74LCX32

Low Voltage Quad 2-Input OR Gate with 5V Tolerant Inputs

General Description

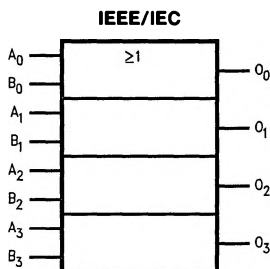
The LCX32 contains four 2-input OR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

The 74LCX32 is fabricated with advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

Features

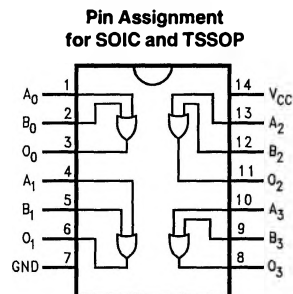
- 5V tolerant inputs
- 5.5 ns t_{PD} max, 10 μ A I_{CCQ} max
- Power down high impedance inputs and outputs
- 2.0V–3.6V V_{CC} supply operation
- ± 24 mA output drive
- Implements patented Quiet Series™ noise/EMI reduction circuitry
- Functionally compatible with 74 series 32
- Latch-up performance exceeds 500 mA
- ESD performance:
 - Human body model > 2000V
 - Machine model > 200V

Logic Symbol



TL/F/12413-1

Connection Diagram



TL/F/12413-2

Pin Names	Description
A_n, B_n	Inputs
O_n	Outputs

	SOIC JEDEC	SOIC EIAJ	TSSOP
Order Number	74LCX32M 74LCX32MX	74LCX32SJ 74LCX32SJX	74LCX32MTC 74LCX32MTCX
NS Package Number	M14A	M14D	MTC14

Preliminary Data: National Semiconductor reserves the right to make changes at any time without notice.

Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.

Symbol	Parameter	Value	Conditions	Units
V _{CC}	Supply Voltage	-0.5 to +7.0		V
V _I	DC Input Voltage	-0.5 to +7.0		V
V _O	DC Output Voltage	-0.5 to V _{CC} + 0.5	Output in High or Low State (Note 2)	V
I _{IK}	DC Input Diode Current	-50	V _I < GND	mA
I _{OK}	DC Output Diode Current	-50 +50	V _O < GND V _O > V _{CC}	mA
I _O	DC Output Source/Sink Current	±50		mA
I _{CC}	DC Supply Current per Supply Pin	±100		mA
I _{GND}	DC Ground Current per Ground Pin	±100		mA
T _{STG}	Storage Temperature	-65 to +150		°C

Note 1: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the "Electrical Characteristics" table are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

Note 2: I_O Absolute Maximum Rating must be observed.

Recommended Operating Conditions

Symbol	Parameter	Min	Max	Units	
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	
V _I	Input Voltage	0	5.5	V	
V _O	Output Voltage	0	V _{CC}	V	
I _{OH} /I _{OL}	Output Current		±24 ±12	mA	
T _A	Free-Air Operating Temperature	-40	85	°C	
Δt/ΔV	Input Edge Rate, V _{IN} = 0.8V-2.0V, V _{CC} = 3.0V	0	10	ns/V	

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = -40°C to +85°C		Units
				Min	Max	
V _{IH}	HIGH Level Input Voltage		2.7-3.6	2.0		V
V _{IL}	LOW Level Input Voltage		2.7-3.6		0.8	V
V _{OH}	HIGH Level Output Voltage	I _{OH} = -100 μA	2.7-3.6	V _{CC} - 0.2		V
		I _{OH} = -12 mA	2.7	2.2		V
		I _{OH} = -18 mA	3.0	2.4		V
		I _{OH} = -24 mA	3.0	2.2		V
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.7-3.6		0.2	V
		I _{OL} = 12 mA	2.7		0.4	V
		I _{OL} = 16 mA	3.0		0.4	V
		I _{OL} = 24 mA	3.0		0.55	V
I _I	Input Leakage Current	0 ≤ V _I ≤ 5.5V	2.7-3.6		±5.0	μA
I _{OFF}	Power-Off Leakage Current	V _I or V _O = 5.5V	0		100	μA
I _{CC}	Quiescent Supply Current	V _I = V _{CC} or GND	2.7-3.6		10	μA
		3.6V ≤ V _I , V _O ≤ 5.5V	2.7-3.6		±10	μA
ΔI _{CC}	Increase in I _{CC} per Input	V _{IH} = V _{CC} - 0.6V	2.7-3.6		500	μA

AC Electrical Characteristics (Preliminary)

Symbol	Parameter	$T_A = -40^{\circ}\text{C to } +85^{\circ}\text{C}$				Units
		$V_{CC} = 3.3\text{V} \pm 0.3\text{V}$		$V_{CC} = 2.7\text{V}$		
		Min	Max	Min	Max	
t_{PHL}	Propagation Delay	1.5	5.5	1.5	6.2	ns
t_{PLH}		1.5	5.5	1.5	6.2	
t_{OSHL}	Output to Output Skew (Note 1)		1.0			ns
t_{OSLH}			1.0			

Note 1: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH to LOW (t_{OSHL}) or LOW to HIGH (t_{OSLH}).

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V_{CC} (V)	$T_A = 25^{\circ}\text{C}$	Unit
				Typical	
V_{OLP}	Quiet Output Dynamic Peak V_{OL}	$C_L = 50\text{ pF}, V_{IH} = 3.3\text{V}, V_{IL} = 0\text{V}$	3.3	0.8	V
V_{OLV}	Quiet Output Dynamic Valley V_{OL}	$C_L = 50\text{ pF}, V_{IH} = 3.3\text{V}, V_{IL} = 0\text{V}$	3.3	0.8	V

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C_{IN}	Input Capacitance	$V_{CC} = \text{Open}, V_I = 0\text{V or } V_{CC}$	7	pF
C_{OUT}	Output Capacitance	$V_{CC} = 3.3\text{V}, V_I = 0\text{V or } V_{CC}$	8	pF
C_{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3\text{V}, V_I = 0\text{V or } V_{CC}, F = 10\text{ MHz}$	25	pF